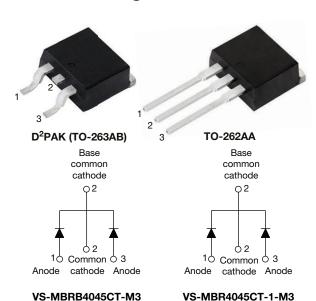
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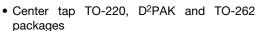
High Performance Schottky Rectifier, 2 x 20 A



PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 20 A					
V _R	45 V					
V _F at I _F	0.58 V					
I _{RM} max.	95 mA at 125 °C					
T _J max.	150 °C					
E _{AS}	20 mJ					
Package	D ² PAK (TO-263AB), TO-262AA					
Circuit configuration	Common cathode					

FEATURES

- 150 °C T_{.I} operation
- Low forward voltage drop
- High frequency operation





- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform (per device)	40	А				
I _{FRM}	T _C = 118 °C (per leg)	40	_ ^				
V _{RRM}		45	V				
I _{FSM}	t _p = 5 μs sine	900	Α				
V _F	20 A _{pk} , T _J = 125 °C	0.58	V				
T _J	Range	-65 to +150	°C				

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-MBRB4045CT-M3 VS-MBR4045CT-1-M3	UNITS		
Maximum DC reverse voltage	V_{R}	45	V		
Maximum working peak reverse voltage	V_{RWM}	45	V		



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ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS		VALUES	UNITS		
Maximum average per le		$T_{\rm C}$ = 118 °C, rated $V_{\rm R}$		20	A		
forward current per device	e I _{F(AV)}			40			
Peak repetitive forward current per leg	I _{FRM}	Rated V _R , square wave, 20 kHz, T _C = 118 °C		40			
Maximum peak one cycle non-repetitiv		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	900	,		
peak surge current per leg	IFSM	10 ms sine or 6 ms rect. pulse		210			
Non-repetitive avalanche energy per le	g E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 3 \text{A}, L = 4.4 \text{mH}$		20	mJ		
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		3	А		

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
		20 A	T _{.1} = 25 °C	0.60	
Maximum forward voltage drop	V _{FM} ⁽¹⁾	40 A	1j=25 C	0.78	V
	VFM ('')	20 A	T _J = 125 °C	0.58	
		40 A	1J = 125 C	0.75	
		T _J = 25 °C		1	
Maximum instantaneous reverse current	I _{RM} ⁽¹⁾	T _J = 100 °C	Rated DC voltage	50	mA
reverse current		T _J = 125 °C		95	
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal rang	ge 100 kHz to 1 MHz), 25 °C	900	pF
Typical series inductance	L _S	Measured from top of term	inal to mounting plane	8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{^{(1)}\,}$ Pulse width $<300~\mu s,$ duty cycle <2~%

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction temperature range	TJ		-65 to 150	°C		
Maximum storage temperature range	T _{Stg}		-65 to 175	C		
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation	1.5			
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, and greased (Only for TO-220)	0.50	°C/W		
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation (For D ² PAK and TO-262)	50			
Approximate weight			2	g		
Approximate weight			0.07	OZ.		
Mounting torque		No. 1 h Soutod thousands	6 (5)	kgf · cm		
Mounting torque maximum		Non-lubricated threads	12 (10)	(lbf \cdot in)		
Marking daying		Case style D ² PAK (TO-263AB)	MBRB4	1045CT		
Marking device		Case style TO-262	MBR40	45CT-1		

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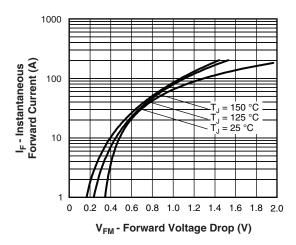


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

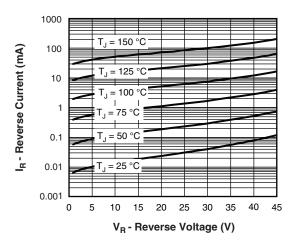


Fig. 2 - Typical Values of Reverse Current vs.Reverse Voltage (Per Leg)

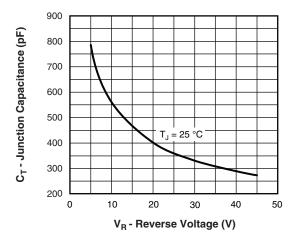


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

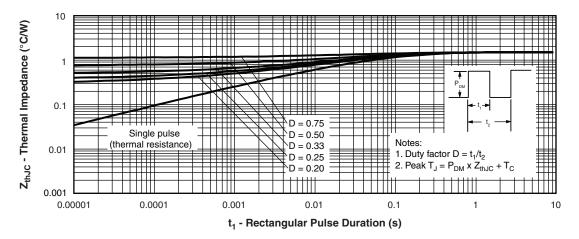


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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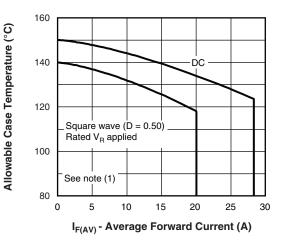


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

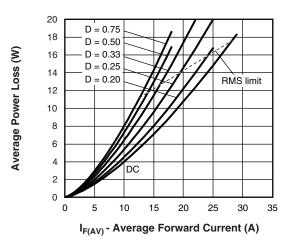


Fig. 6 - Forward Power Loss Characteristics

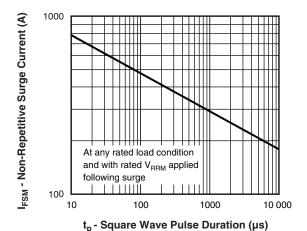


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

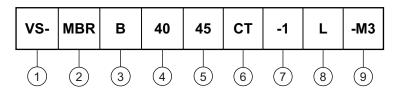
Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D)}; I_R \text{ at } V_{R1} = \text{rated } V_R \text{ (1 - D)}; I_R \text{ (2 - C)}; \\ I_R \text{ (2 - C)} & I_R \text{ (2 - C)}; I_R \text{ (3 - C)}; I_R \text{ (4 - C)$

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Essential part number

• None = TO-262 7 = -1

- Current rating (40 = 40 A)

5 - Voltage rating (45 = 45 V)

6 - CT = essential part number

- • None = D^2PAK 3 = B

• -1 = TO-262 **3** None

8 - • None = tube

• L = tape and reel (left oriented - for D²PAK only)

• R = tape and reel (right oriented - for D2PAK only)

9 - -M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION				
VS-MBRB4045CTL-M3	800	13" diameter plastic tape and reel				
VS-MBRB4045CT-M3	50	Antistatic plastic tubes				
VS-MBRB4045CTR-M3	800	13" diameter plastic tape and reel				
VS-MBR4045CT-1-M3	50	Antistatic plastic tubes				

	LINKS TO RELATED DOCUMENTS						
Dimensions —	D ² PAK (TO-263AB)	www.vishay.com/doc?96164					
Differisions —	TO-262AA	www.vishay.com/doc?96165					
Dort modeling information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444					
Part marking information —	TO-262AA	www.vishay.com/doc?95443					
Packaging information		www.vishay.com/doc?96424					
SPICE model		www.vishay.com/doc?95296					



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D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	ETERS	INC	HES	NOTES		SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inches
- (7) Outline conforms to JEDEC® outline TO-263AB

Revision: 13-Jul-17 Document Number: 96164



Vishay Semiconductors

TO-262AA

DIMENSIONS in millimeters and inches

Modified JEDEC® outline TO-262







⊕ 0.010 **M** A**M** B

Lead assignments



Diodes 1. - Anode (two die)/open (one die)

2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

SYMBOL	MILLIM	IETERS	INC	NOTES			
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES		
Α	4.06	4.83	0.160	0.190			
A1	2.03	3.02	0.080	0.119			
b	0.51	0.99	0.020	0.039			
b1	0.51	0.89	0.020	0.035	4		
b2	1.14	1.78	0.045	0.070			
b3	1.14	1.73	0.045	0.068	4		
С	0.38	0.74	0.015	0.029			
c1	0.38	0.58	0.015	0.023	4		
c2	1.14	1.65	0.045	0.065			
D	8.51	9.65	0.335	0.380	2		
D1	6.86	8.00	0.270	0.315	3		
E	9.65	10.67	0.380	0.420	2, 3		
E1	7.90	8.80	0.311	0.346	3		
е	2.54 BSC		0.100) BSC			
L	13.46	14.10	0.530	0.555			
L1	-	1.65	-	0.065	3		
L2	3.56	3.71	0.140	0.146			

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
 (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- Controlling dimension: inches
- Outline conform to JEDEC® TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), L1 (max.), L2 (min., max.)



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